This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

- 1 1. (previously presented): A method for fabricating a magnetic head including a spin valve
- 2 sensor, comprising the steps of:
- 3 fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1);
- 4 fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve
- 5 sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned
- 6 magnetic layer and at least one free magnetic layer;
- 7 wherein said seed layer is a three part seed layer comprised of Al₂O₃, NiMnO and
- 8 NiFeCr, and wherein said NiFeCr seed layer has a rough top crystallographic surface that is
- 9 rougher than a top crystallographic surface of a deposited NiFeCr seed layer.
- 1 2. (previously presented): A method for fabricating a magnetic head as described in claim 1
- 2 wherein said NiFeCr seed layer portion is fabricated to have a thickness of approximately 20 Å,
- 3 and wherein said rough top crystallographic surface is formed by etching a previously deposited
- 4 NiFeCr top surface.
- 1 3. (original): A method for fabricating a magnetic head as described in claim 1 wherein said
- 2 spin valve sensor layers include at least one pinned magnetic layer having a composition
- 3 including CoFe and at least one spacer layer having a composition including Cu, and at least one
- 4 free magnetic layer having a composition including NiFe.

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(original): A method for fabricating a magnetic head as described in claim 1 wherein the

Cr concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%. 2

(original): A method for fabricating a magnetic head as described in claim 4 wherein the 1 5

Cr concentration of said NiFeCr layer is approximately 38 at.%.

(original): A method for fabricating a magnetic head as described in claim 5 wherein the

composition of said NiFeCr layer is approximately Ni49 5 Fe12 5 Cr38. 2

7. (withdrawn): A method for fabricating a magnetic head including a spin valve sensor,

2 comprising the steps of:

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fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1); 3

fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve

sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned 5

6 magnetic layer and at least one free magnetic layer;

7 wherein said seed layer is comprised of Al₂O₃, NiMnO, NiFeCr layer portions, and

8 wherein said NiFeCr layer is fabricated by depositing it to a first thickness and subsequently

etching it back to a final thickness before the fabrication of said PtMn layer. 9

(withdrawn): A method for fabricating a magnetic head as described in claim 7 wherein 1

2 said NiFeCr layer is fabricated to have a final thickness of from approximately 10 Å to

3 approximately 40 Å.

- 1 9. (withdrawn): A method for fabricating a magnetic head as described in claim 8 wherein
- 2 said NiFeCr seed layer is fabricated to have a final thickness of from approximately 15 Å to
- 3 approximately 35 Å.
- 1 10. (withdrawn): A method for fabricating a magnetic head as described in claim 9 wherein
- 2 said NiFeCr layer is fabricated to have a final thickness of approximately 20 Å.
- 1 11. (withdrawn): A method for fabricating a magnetic head as described in claim 7 wherein
- 2 said first thickness of said NiFeCr layer is from approximately 15 Å to approximately 45 Å and
- 3 it is etched back a thickness of from approximately 5 Å to approximately 15 Å.
- 1 12. (withdrawn): A method for fabricating a magnetic head as described in claim 11 wherein
- 2 said first thickness is approximately 30 Å and said final thickness is approximately 20 Å.
- 1 13. (withdrawn): A method for fabricating a magnetic head as described in claim 7 wherein
- 2 said spin valve sensor layers include at least one pinned magnetic layer having a composition
- 3 including CoFe and at least one spacer layer having a composition including Cu, and at least one
- 4 free magnetic layer having a composition including NiFe.
- 1 14. (withdrawn): A method for fabricating a magnetic head as described in claim 7 wherein
- 2 the Cr concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46
- 3 at.%.

- 1 15. (withdrawn): A method for fabricating a magnetic head as described in claim 14 wherein
- 2 the Cr concentration of said NiFeCr layer is approximately 38 at.%.
- 1 16. (withdrawn): A method for fabricating a magnetic head as described in claim 15 wherein
- 2 the composition of said NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- 1 17. (withdrawn): A method for fabricating a magnetic head as described in claim 7 wherein
- 2 said first thickness is from 15 to 45 Å, and it is etched back a thickness of from 5 to 15 Å, and
- 3 wherein the Cr concentration of said NiFeCr layer composition is from approximately 35 at.% to
- 4 approximately 46 at.%.
- 1 18. (previously presented): A magnetic head including a spin valve sensor comprising:
- 2 a magnetic shield layer (S1) being fabricated above a substrate base;
- 3 a first electrical insulation layer (G1) being fabricated above said S1 layer;
- 4 a spin valve sensor structure being disposed above said G1 layer;
- 5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- 6 G1 layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic
- 7 layer and at least one free magnetic layer being disposed above said PtMn layer; and
- 8 wherein said seed layer includes an Al₂O₃ layer, an NiMnO layer, and an NiFeCr layer,
- 9 and wherein said NiFeCr seed layer has a rough top crystallographic surface that is rougher than
- 10 a top crystallographic surface of a deposited NiFeCr seed layer.

- (original): A magnetic head as described in claim 18 wherein said NiFeCr layer is
- formed with a thickness of approximately 20 Å. 2
- 20. (original): A magnetic head as described in claim 18 wherein the Cr concentration of
- said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- (original): A magnetic head as described in claim 19 wherein the Cr concentration of 21
- 2 said NiFeCr layer is approximately 38 at.%.
 - (original): A magnetic head as described in claim 21 wherein the composition of said 22.
- NiFeCr layer is approximately Ni49 5 Fe17 5 Cr38. 2
- (currently amended): A magnetic head including a spin valve sensor comprising: 1 23.
- a magnetic shield layer (S1) being fabricated above a substrate base; 2
- a first electrical insulation layer (G1) being fabricated above said S1 layer; 3
- a spin valve sensor structure being disposed above said G1 layer; 4
- 5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- GI layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic 6
- layer and at least one free magnetic layer being disposed above said PtMn layer; and 7
- wherein said seed layer is comprised of NiFeCr having a rough top crystallographic 8
- surface that is rougher than a top crystallographic surface of a deposited NiFeCr seed layer. 9

- 1 24. (original): A magnetic head as described in claim 23 wherein said NiFeCr layer is
- 2 formed with a thickness of from approximately 10 Å to approximately 40 Å.
- 1 25. (original): A magnetic head as described in claim 23 wherein said NiFeCr seed layer is
- 2 formed with a thickness of from approximately 15 Å to approximately 35 Å.
- 1 26. (original): A magnetic head as described in claim 23 wherein said NiFeCr layer is
- 2 formed with a thickness of approximately 20 Å.
- 1 27. (original): A magnetic head as described in claim 23 wherein the Cr concentration of
- 2 said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- 1 28. (original): A magnetic head as described in claim 27 wherein the Cr concentration of
- 2 said NiFeCr layer is approximately 38 at.%.
- 1 29. (original): A magnetic head as described in claim 28 wherein the composition of said
- 2 NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.
- 1 30. (original): A magnetic head as described in claim 23 wherein said spin valve sensor
- 2 structure includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer
- 3 having a composition which includes CoFe, at least one spacer layer having a composition which
- 4 includes Cu, and at least one free magnetic layer having a composition which includes NiFe.

- 1 31. (previously presented): A hard disk drive, including at least one magnetic head having a
- 2 read head portion comprising:
- 3 a magnetic shield layer (S1) being fabricated above a substrate base;
- 4 a first electrical insulation layer (G1) being fabricated above said S1 layer;
- 5 a spin valve sensor structure being disposed above said G1 layer;
- 6 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- 7 Gl layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic
- 8 layer and at least one free magnetic layer; and
- 9 wherein said seed layer includes an Al₂O₃ layer, an NiMnO layer and an NiFeCr layer,
- 10 and wherein said NiFeCr seed layer has a top surface with a rough crystallographic surface that
- is rougher than a top crystallographic surface of a deposited NiFeCr seed layer.
 - 1 32. (original): A hard disk drive as described in claim 31 wherein said NiFeCr layer has a
 - 2 thickness of approximately 20 Å.
- 1 33. (original): A hard disk drive as described in claim 31 wherein the Cr concentration of
- 2 said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- 1 34. (original): A hard disk drive as described in claim 33 wherein the Cr concentration of
- 2 said NiFeCr layer is approximately 38 at.%.
- 1 35. (original): A hard disk drive as described in claim 34 wherein the composition of said
- NiFeCr layer is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.

- 1 36. (previously presented): A hard disk drive, including at least one magnetic head having a
- 2 read head portion comprising:
- 3 a magnetic shield layer (S1) being fabricated above a substrate base;
- 4 a first electrical insulation layer (G1) being fabricated above said S1 layer;
- 5 a spin valve sensor structure being disposed above said G1 layer;
- 6 wherein said spin valve sensor structure includes a seed layer being fabricated above said
- 7 G1 layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic
- 8 layer and at least one free magnetic layer; and
- 9 wherein said seed layer has an upper surface comprised of NiFeCr having a rough top
- 10 crystallographic surface that is rougher than a top crystallographic surface of a deposited NiFeCr
- 11 seed layer.
 - 1 37. (original): A hard disk drive as described in claim 36 wherein NiFeCr seed layer is
 - 2 formed with a thickness of from approximately 10 Å to approximately 40 Å.
 - 1 38. (original): A hard disk drive as described in claim 36 wherein said NiFeCr seed layer is
 - 2 formed with a thickness of from approximately 15 Å to approximately 35 Å.
 - 1 39 (original): A hard disk drive as described in claim 36 wherein said NiFeCr layer is
 - 2 formed with a thickness of approximately 20 Å.
 - 1 40. (original): A hard disk drive as described in claim 36 wherein the Cr concentration of
 - 2 said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.

- 1 41. (original): A hard disk drive as described in claim 40 wherein the Cr concentration of
- 2 said NiFeCr layer is approximately 38 at.%.
- 1 42. (original): A hard disk drive as described in claim 41 wherein the composition of said
- NiFeCr layer is approximately Ni_{49,5} Fe_{12,5} Cr₃₈.
- 1 43. (original): A hard disk drive as described in claim 36 wherein said spin valve sensor
- 2 structure includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer
- 3 having a composition which includes CoFe, at least one spacer layer having a composition which
- 4 includes Cu, and at least free magnetic layer having a composition which includes NiFe.